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## $\label{lem:continuous} Low-Temperature\ Growth\ of\ Ultrathin\ and\ Epitaxial\ Mo_2C$ $nanosheets\ via\ the\ Vapor-Liquid-Solid\ Process$

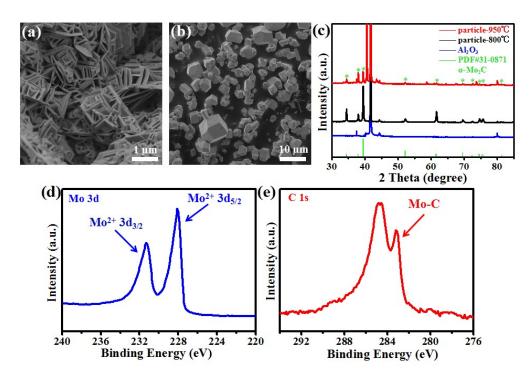
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**Figure S1** (a) and (b) SEM images of the  $MoC_x$  crystals grown at 800 and 950 °C, respectively. (c) The corresponding XRD patterns of the  $MoC_x$  crystals. (d) and (e) XPS spectra acquired at the Mo 3d and C 1s regions.

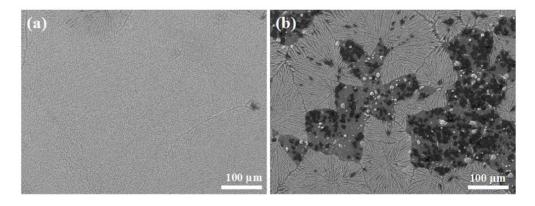
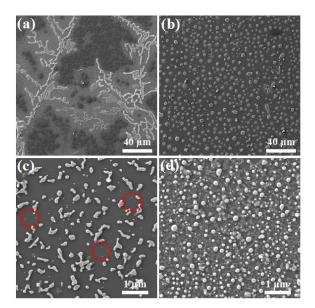


Figure S2 SEM images of the spin-coated  $Na_2MoO_4$  aqueous solution on the  $Al_2O_3(0001)$  with (a) or without (b)  $O_2$  plasma.



**Figure S3** SEM images of the spin-coated  $Na_2MoO_4$  aqueous solution at 800 °C (a) without annealing, (b) with an annealing process for 20 min. (c) and (d) SEM images of the  $Mo_2C$  crystals grown at 1000 and 1100 °C, respectively.